Small Signal Diodes

1N4148WS, 1N4448WS, 1N914BWS

Features

- General Purpose Diodes
- Fast Switching Device (T_{RR} < 4.0 ns)
- Very Small and Thin SMD Package
- Moisture Level Sensitivity 1
- Matte Tin (Sn) Lead Finish
- Green Mold Compound
- These Devices are Pb-Free and are RoHS Compliant

ABSOLUTE MAXIMUM RATINGS

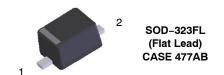
Parameter	Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage	V_{RSM}	100	٧
Repetitive Peak Reverse Voltage	V_{RRM}	75	V
Repetitive Peak Forward Current	I _{FRM}	300	mA
Continuous Forward Current	Io	150	mA
Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 s Pulse Width = 1.0 μs	I _{FSM}	1.0 4.0	Α
Operating Junction Temperature	T_J	+150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



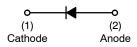
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Band Indicates Cathode

ELECTRICAL SYMBOL



DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 3 of this data sheet.

ORDERING INFORMATION

See detailed ordering and shipping information on page 3 of this data sheet.

THERMAL CHARACTERISTICS (Values are at T_A = 25°C unless otherwise noted.)

Symbol	Parameter	Value	Unit
P_{D}	Power Dissipation (T _C = 25°C)	200	mW
$R_{ hetaJA}$	Thermal Resistance, Junction-to-Ambient (Note 1)	500	°C/W

^{1.} Device mounted on FR-4 PCB minimum land pad.

ELECTRICAL CHARACTERISTICS (Values are at T_A = 25°C unless otherwise noted.)

Symbol	Parameter		Conditions	Min	Max	Unit
BV _R	Breakdown Voltage		I _R = 100 μA	100	-	V
			I _R = 5 μA	75	-	
I _R	Reverse Current		V _R = 20 V	-	25	nA
			V _R = 75 V	İ	5	μΑ
V _F	Forward Voltage	1N4448WS / 1N914BWS	I _F = 5 mA	0.62	0.72	V
		1N4148WS	I _F = 10 mA	-	1	
		1N4448WS / 1N914BWS	I _F = 100 mA	-	1	
Co	Diode Capacitance		V _R = 0, f = 1.0 MHz	-	4	pF
T _{RR}	Reverse Recovery Time		I_F = 10 mA, I_R = 60 mA, I_{RR} = 1 mA, R_L = 100 Ω	-	4	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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TYPICAL CHARACTERISTICS

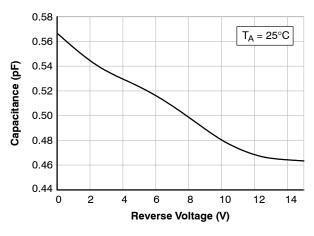


Figure 1. Total Capacitance

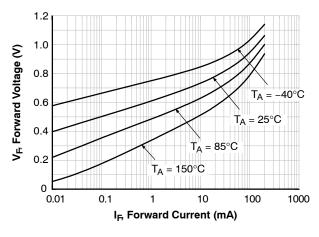


Figure 2. Forward Voltage vs. Ambient Temperature

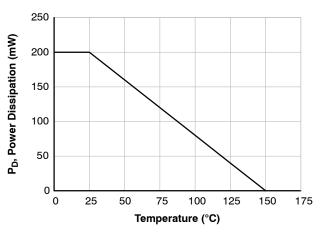


Figure 3. Power Derating Curve

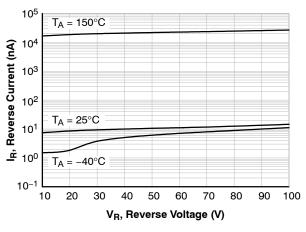


Figure 4. Reverse Current vs. Reverse Voltage

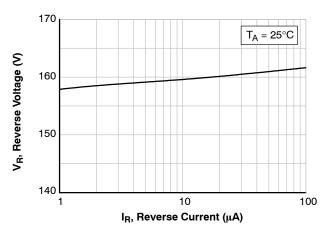
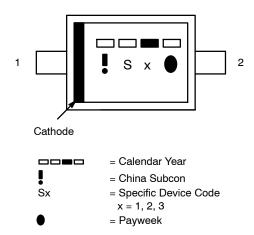


Figure 5. Reverse Voltage vs. Reverse Current

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MARKING DIAGRAM



ORDERING INFORMATION

Part Number	Top Mark	Package	Shipping [†]
1N4148WS	S1	SOD-323FL	3000 / Tape & Reel
1N4448WS	S2	(Pb-Free)	
1N914BWS	S3		

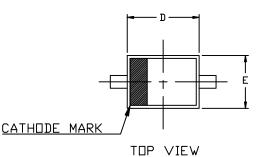
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

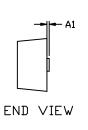


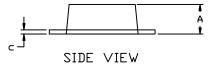


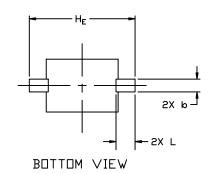
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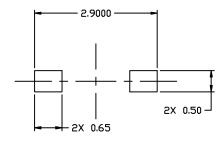




NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. LEAD THICKNESS INCLUDES LEAD FINISH.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS		
DIM	MIN.	NDM	MAX.
Α	0.60	0.70	0.90
A1	0.00	0.05	0.10
b	0.25	0.30	0.35
С	0.05	0.10	0.20
D	1.60	1.70	1.80
E	1.15	1.25	1.35
HE	2.30	2.50	2.70
L	0.35	0.45	0.55



RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the IDN Semiconductor Soldering and Mounting Techniques Reference Manual, SILDERRM/D.

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